

General Description

The Sanrise SRC60R140BS is a high voltage power MOSFET, fabricated using advanced super junction technology. The resulting device has extremely low on resistance, low gate charge and fast switching time, making it especially suitable for applications which require superior power density and outstanding efficiency.

The SRC60R140BS break down voltage is 600V and it has a high rugged avalanche characteristics. The SRC60R140BS is available in TO-220F, TO-220C, TO-263-2 and TO-247 packages.

Features

- Ultra Low $R_{DS(ON)} = 150m\Omega @ V_{GS} = 10V$.
- Ultra Low Gate Charge, $Q_g = 40.4nC$ typ.
- Intrinsic Fast-Recovery Body Diode
- Fast switching capability
- Robust design with better EAS performance
- Non-automotive Qualified
- Ultra-fast body diode

Application

- AC/DC Power Supply
- PC Power
- Sever / Telecom
- Solar Inverter

Ordering Information

SRC60R140BS□□-□			
Circuit Type	_____	E: Lead Free	
Package	_____	G: Green	
TF: TO-220F		Blank: Tube	
TC: TO-220C		TR: Tape & Reel	
S2: TO-263-2			
T: TO-247			

Symbol

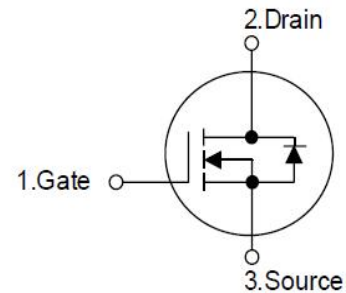


Figure 1 Symbol of SRC60R140BS

Package Type

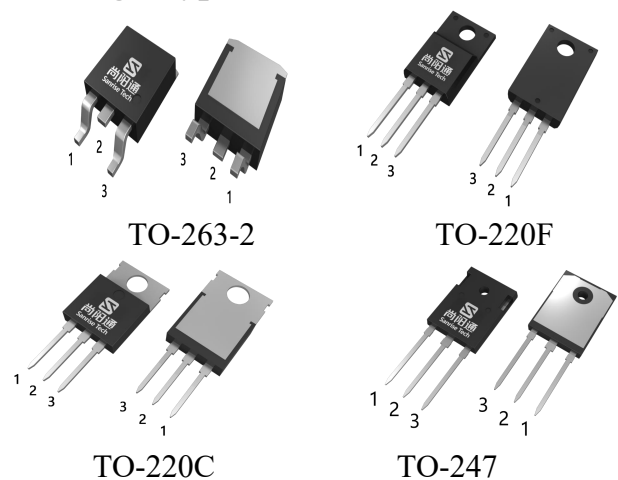


Figure 2 Package Types of SRC60R140BS

Package	Part Number		Marking ID		Packing Type
	Lead Free	Green	Lead Free	Green	
TO-220F	SRC60R140BSTF-E	SRC60R140BSTF-G	SRC60R140BSTFE	SRC60R140BSTFG	Tube
TO-220C	SRC60R140BSTC-E	SRC60R140BSTC-G	SRC60R140BSTCE	SRC60R140BSTCG	Tube
TO-263-2	SRC60R140BSS2TR-E	SRC60R140BSS2TR-G	SRC60R140BSS2E	SRC60R140BSS2G	Tape & Reel
TO-247	SRC60R140BST-E	SRC60R140BST-G	SRC60R140BSTE	SRC60R140BSTG	Tube

Absolute Maximum Ratings^{Note 1}

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	600	V
Gate-Source Voltage(static)		V_{GS}	±30	V
Gate-Source Voltage(dynamic),AC(f>1Hz)		V_{GS}	±30	
Continuous Drain Current	$T_C=25^{\circ}\text{C}$	I_D	25.0	A
	$T_C=100^{\circ}\text{C}$		15.8	
	$T_C=125^{\circ}\text{C}$		11.2	
Power Dissipation ($T_C=25^{\circ}\text{C}$,TO-220C,TO-247,TO-263-2)		P_{tot}	178.6	W
Power Dissipation ($T_C=25^{\circ}\text{C}$,TO-220F)		P_{tot}	34.7	W
Pulsed Drain Current (Note 2)		I_{DM}	76	A
Avalanche Energy, Single Pulse (Note 3)		E_{AS}	410	mJ
Avalanche Energy, Repetitive (Note 2)		E_{AR}	0.7	mJ
Avalanche Current, Repetitive (Note 2)		I_{AR}	3.5	A
Continuous Diode Forward Current		I_S	25.0	A
Diode Pulse Current		$I_{S,PULSE}$	76	A
MOSFET dv/dt Ruggedness, $V_{DS}\leq 480\text{V}$		dv/dt	50	V/ns
Reverse Diode dv/dt, $V_{DS}\leq 480\text{V}$, $I_{SD}\leq I_D$		dv/dt	50	V/ns
Operating Junction Temperature		T_J	150	°C
Storage Temperature		T_{STG}	-55 to 150	°C
Lead Temperature (Soldering, 10 sec)		T_{LEAD}	260	°C

Note:

1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. Repetitive Rating: Pulse width limited by maximum junction temperature
3. $I_{AS} = 3.5\text{A}$, $V_{DD} = 60\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}\text{C}$

Thermal characteristics

Parameter		Symbol	Min	Typ	Max	Unit
Thermal resistance, Junction-to-Case	TO-220F	R_{thJC}			3.6	°C /W
	TO-247				0.7	
	TO-220C				0.7	
	TO-263-2				0.7	
Thermal resistance, Junction-to-Ambient	TO-220F	R_{thJA}			80	°C /W
	TO-247				62	
	TO-220C				62	
	TO-263-2				62	

Electrical Characteristics

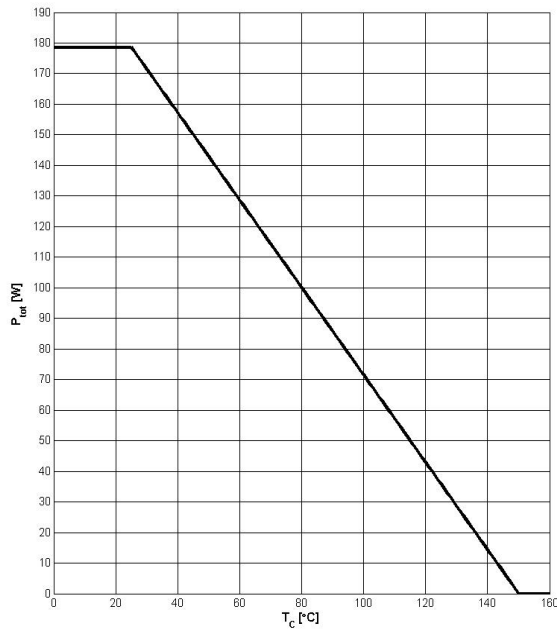
$T_J = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Statistic Characteristics							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250uA	600			V
Zero Gate Voltage Drain Current		I _{DSS}	V _{DS} =600V, V _{GS} =0V			10	uA
Gate-Body Leakage Current	Forward	I _{GSSF}	V _{GS} =30V, V _{DS} =0V			100	nA
	Reverse	I _{GSSR}	V _{GS} =-30V, V _{DS} =0V			-1.0	uA
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250uA	2.3	3.3	4.3	V
Static Drain-Source On-Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =10A		123	150	mΩ
Gate Resistance		R _G	f=1MHz, Open Drain		1.7		Ω
Dynamic Characteristics							
Input Capacitance		C _{ISS}	V _{DS} =50V, V _{GS} =0V, f=1MHz		1650		pF
Output Capacitance		C _{OSS}			129.6		
Reverse Transfer Capacitance		C _{RSS}			10.1		
Effective output capacitance, energy related ^{NOTE5}		C _{O(er)}	V _{GS} =0V, V _{DS} =0...480V		76.8		pF
Effective output capacitance, time related ^{NOTE6}		C _{O(tr)}			281		
Turn-on Delay Time		t _{d(on)}	V _{DD} =400V, I _D =13.0A R _G =3.4Ω, V _{GS} =10V		11		ns
Rise Time		t _r			10		
Turn-off Delay Time		t _{d(off)}			76		
Fall Time		t _f			8		
Gate Charge Characteristics							
Gate to Source Charge		Q _{gs}	V _{DD} =480V, I _D =13.0A V _{GS} =0 to 10V		10.8		nC
Gate to Drain Charge		Q _{gd}			13.9		
Gate Charge Total		Q _g			40.4		
Gate Plateau Voltage		V _{plateau}			5.4		V
Reverse Diode Characteristics							
Drain-Source Diode Forward Voltage		V _{SD}	V _{GS} =0V, I _{SD} =10A		0.90	1.1	V
Reverse Recovery Time		t _{rr}	V _R =400V, I _F =13.0A dI _F /dt=130.0A/us		129		ns
Reverse Recovery Charge		Q _{rr}			1		uC
Peak Reverse Recovery Current		I _{rrm}			13.5		A

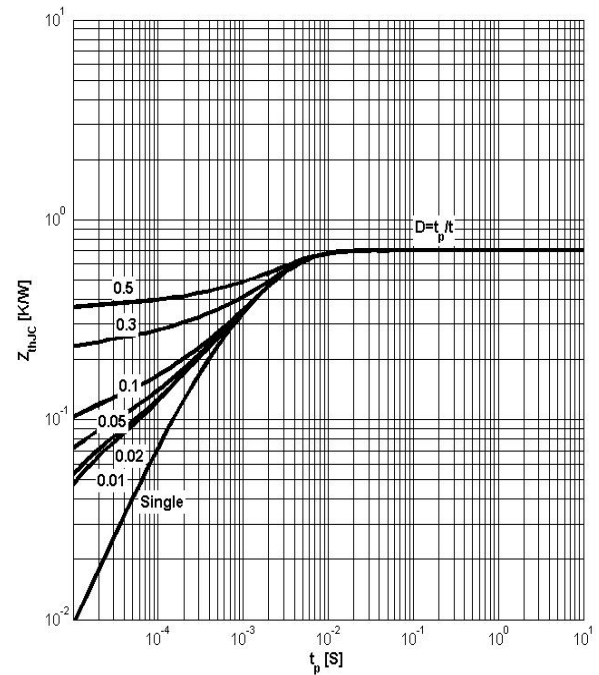
Note:

5. $C_{O(er)}$ is a fixed capacitance that gives the same stored energy as C_{OSS} while V_{DS} is rising from 0 to 480V

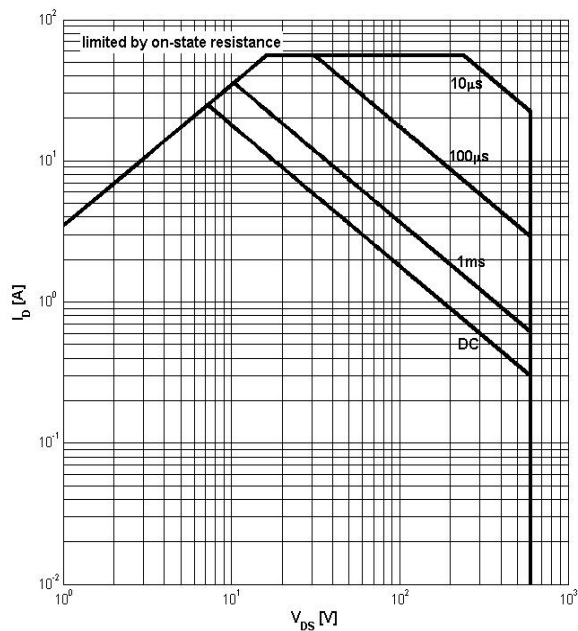
6. $C_{O(tr)}$ is a fixed capacitance that gives the same charging time as C_{OSS} while V_{DS} is rising from 0 to 480 V

Typical Performance Characteristics
Figure 3: Power Dissipation


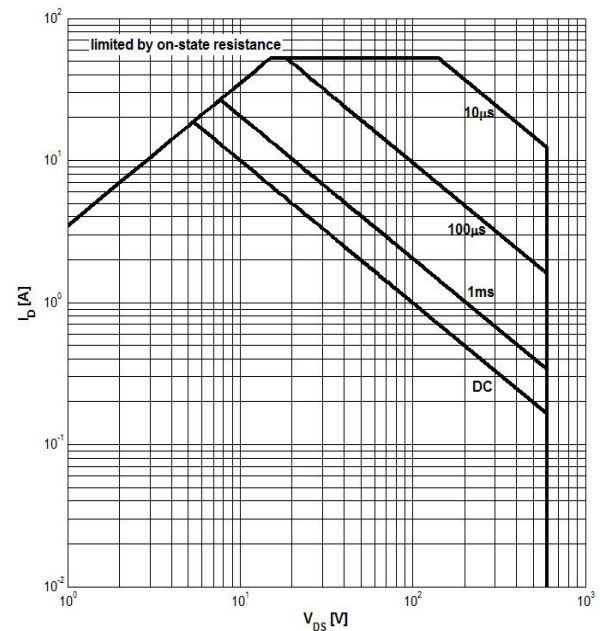
$$P_{tot} = f(T_c)$$

Figure 4: Max. Transient Thermal Impedance


$$Z_{(th)JC} = f(t_p); \text{ parameter: } D = t_p/T$$

Figure 5: Safe Operating Area


$$I_D = f(V_{DS}); T_c = 25^\circ\text{C}; V_{GS} > 7\text{V}; \text{ parameter } t_p$$

Figure 6: Safe Operating Area


$$I_D = f(V_{DS}); T_c = 80^\circ\text{C}; V_{GS} > 7\text{V}; \text{ parameter } t_p$$

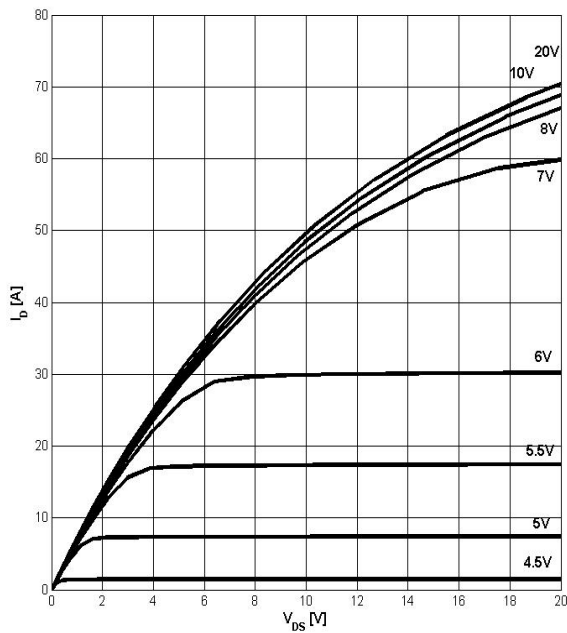
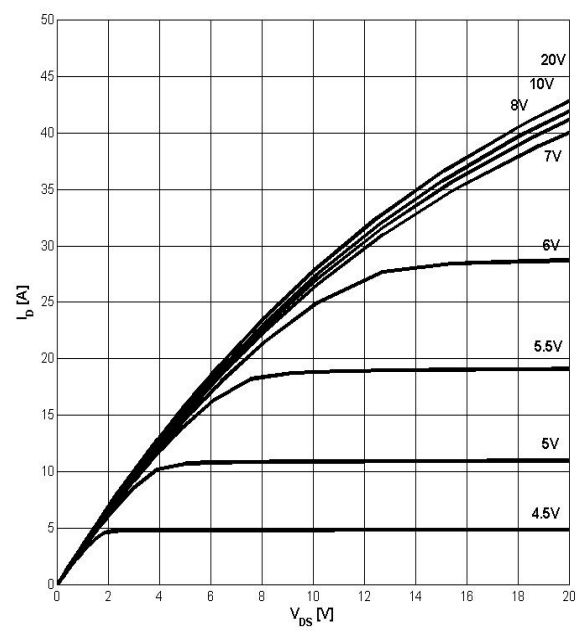
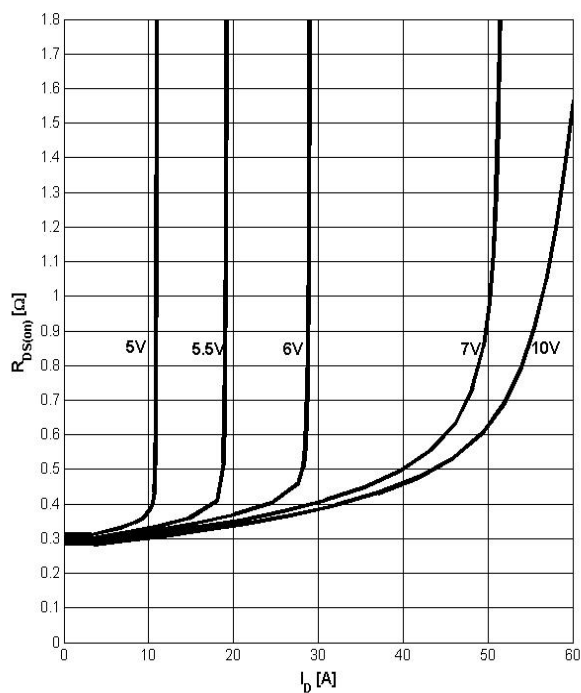
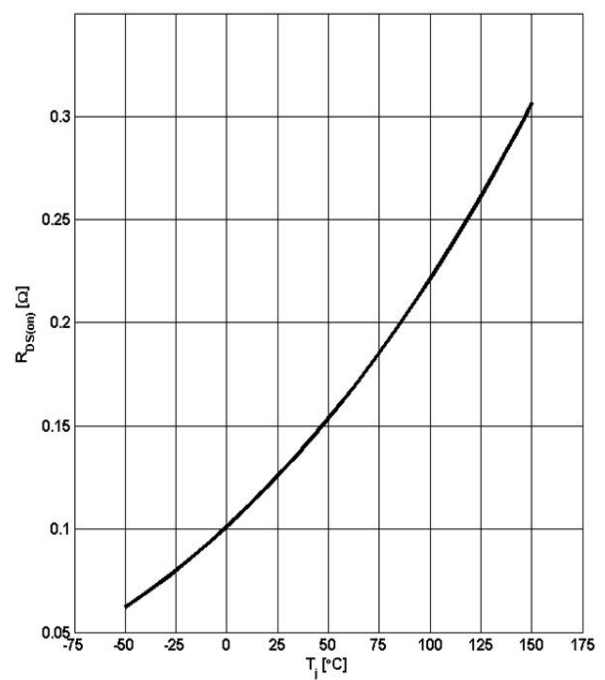
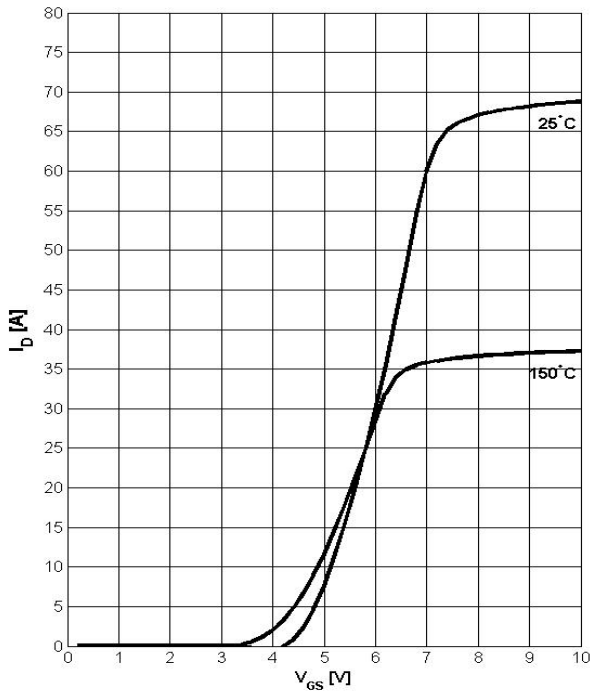
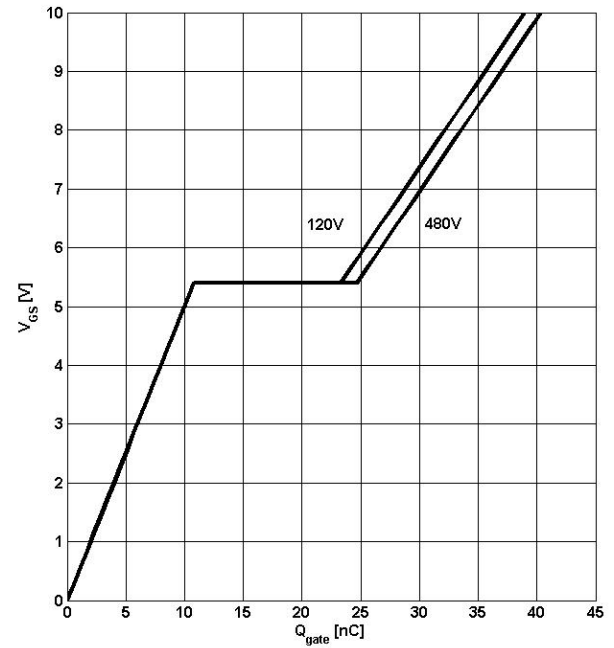
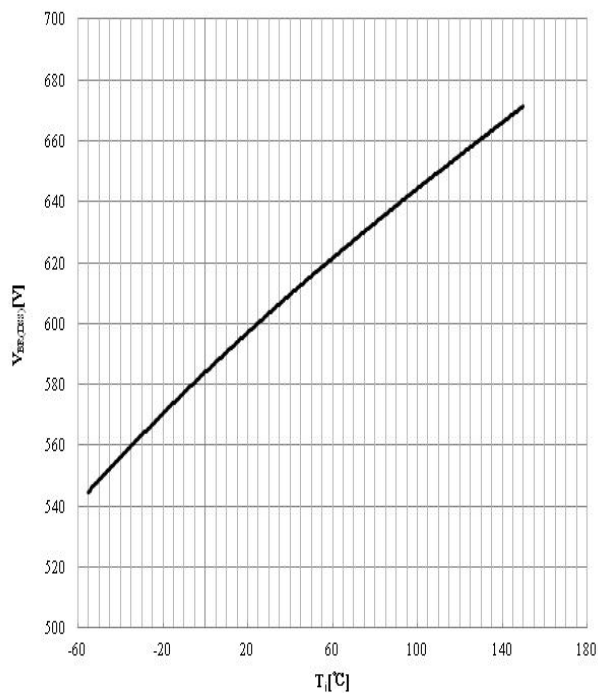
Figure 7: Typ. Output Characteristics

 $I_D = f(V_{DS}); T_j = 25^\circ\text{C}; \text{parameter: } V_{GS}$
Figure 8: Typ. Output Characteristics

 $I_D = f(V_{DS}); T_j = 125^\circ\text{C}; \text{parameter: } V_{GS}$
Figure 9: Typ. Drain-Source On-State Resistance

 $R_{DS(ON)} = f(I_D); T_j = 125^\circ\text{C}; \text{parameter: } V_{GS}$
Figure 10: Typ. Drain-Source On-State Resistance

 $R_{DS(ON)} = f(T_j); I_D = 13\text{A}; V_{GS} = 10\text{V}$

Figure 11: Typ. Transfer Characteristics


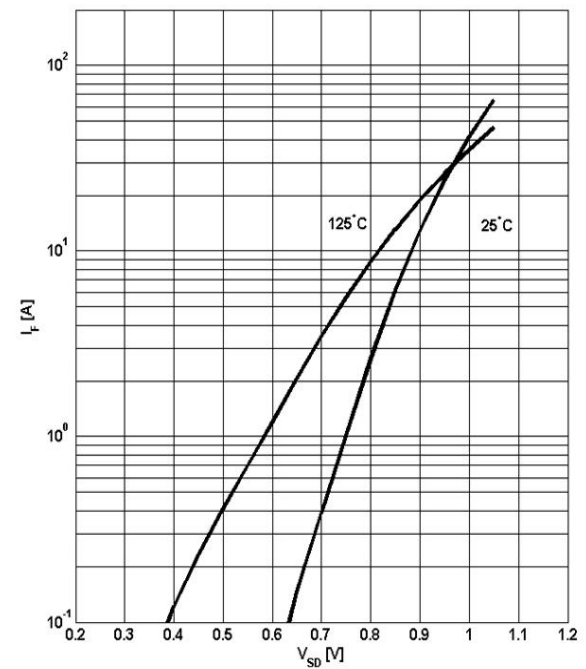
$$I_D = f(V_{GS}); V_{DS} = 20V$$

Figure 12: Typ. Gate Charge


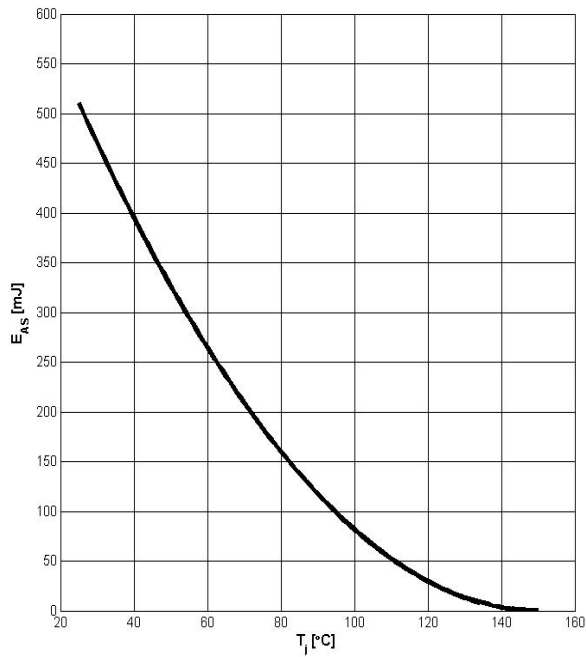
$$V_{GS} = f(Q_{gate}), I_D = 13A \text{ pulsed}$$

Figure 13: Drain-Source Breakdown Voltage


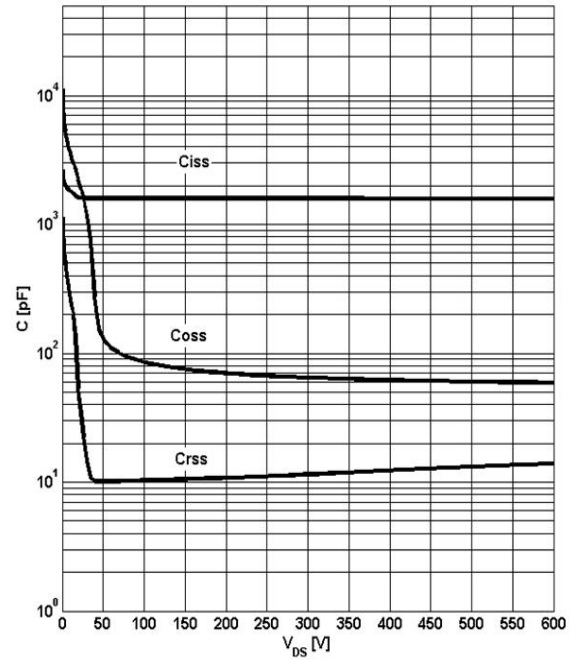
$$V_{BR(DSS)} = f(T_j); I_D = 10mA$$

Figure 14: Forward Characteristics of Reverse Diode


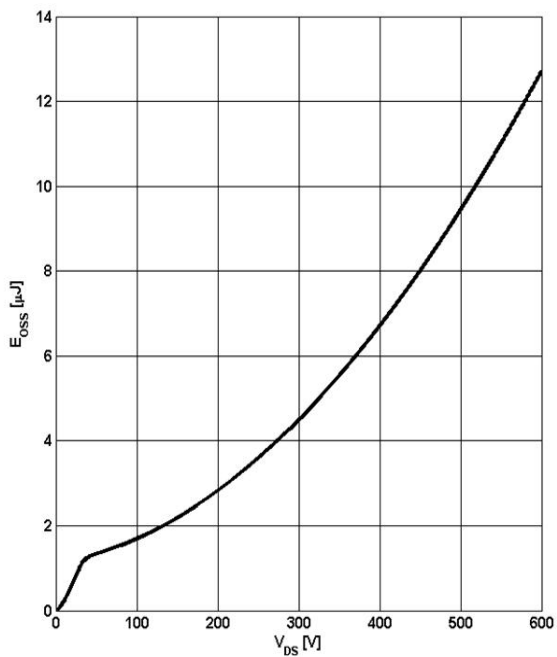
$$I_R = f(V_{SD}); \text{parameter: } T_j$$

Figure 15: Avalanche Energy


$$E_{AS}=f(T_J); I_D=3.6A; V_{DD}=60V$$

Figure 16: Typ. Capacitances


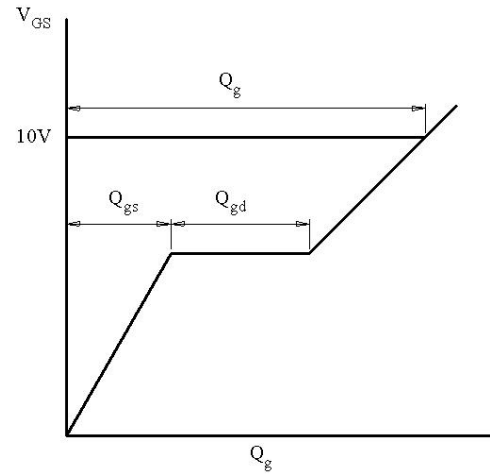
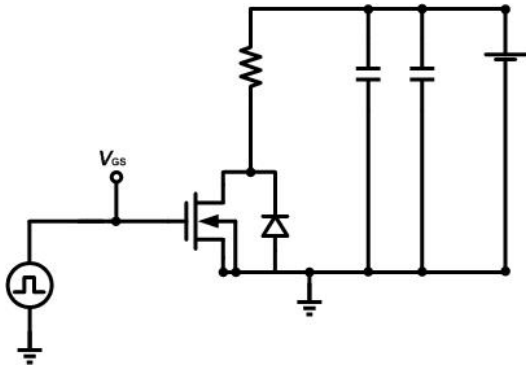
$$C=f(V_{DS}); V_{GS}=0; f=1MHz$$

Figure 17: Coss Stored Energy


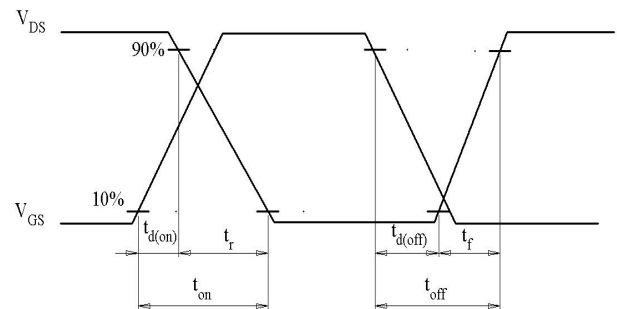
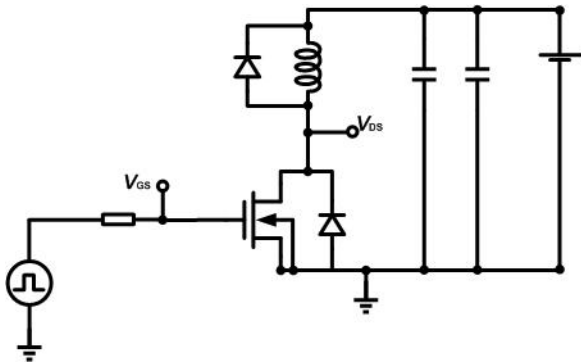
$$E_{OSS}=f(V_{DS})$$

Test Circuits

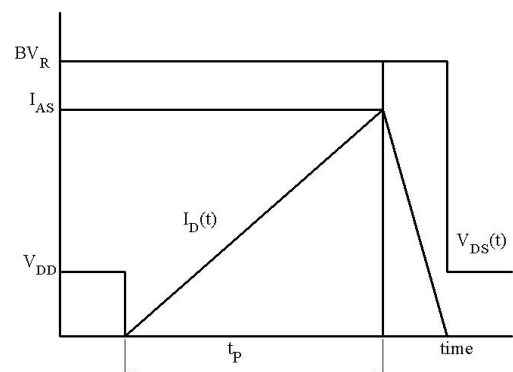
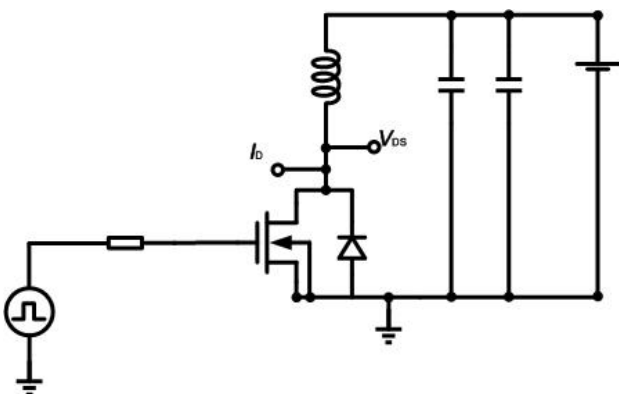
1. Gate Charge Test Circuit & Waveform



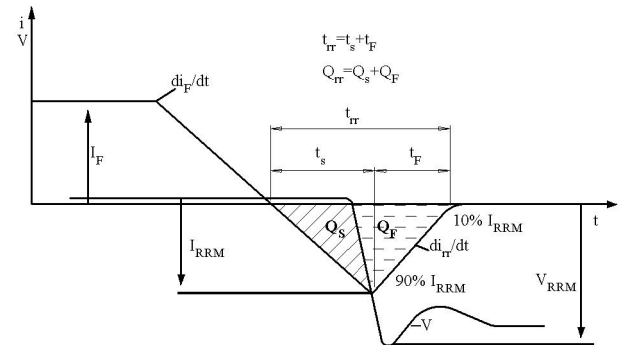
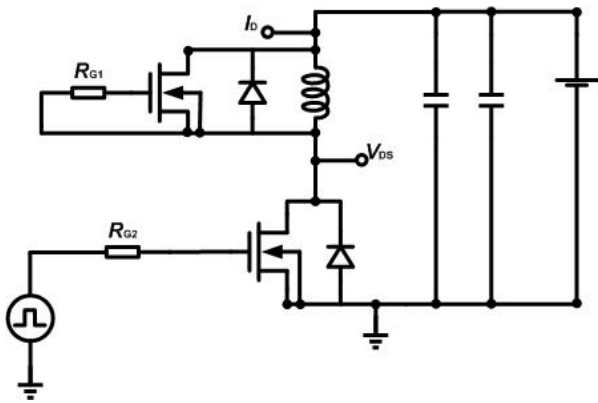
2. Switch Time Test Circuit

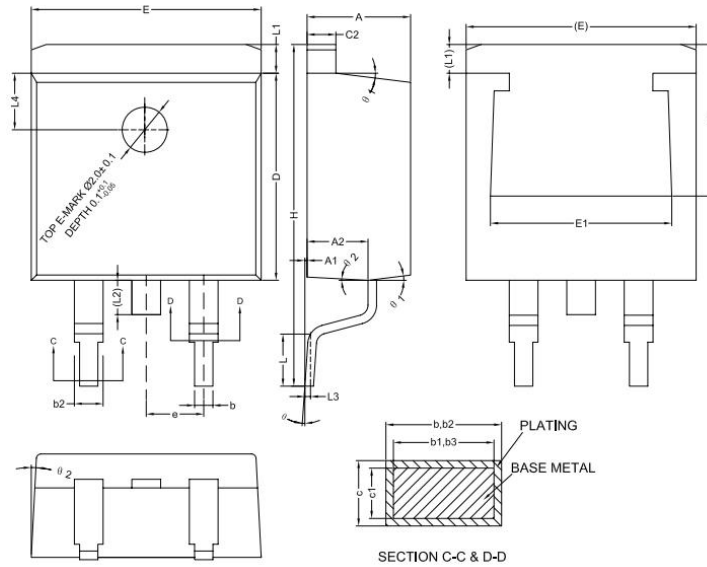


3. Unclaimed Inductive Switching Test Circuit & Waveforms



4. Test Circuit and Waveform for Diode Characteristics

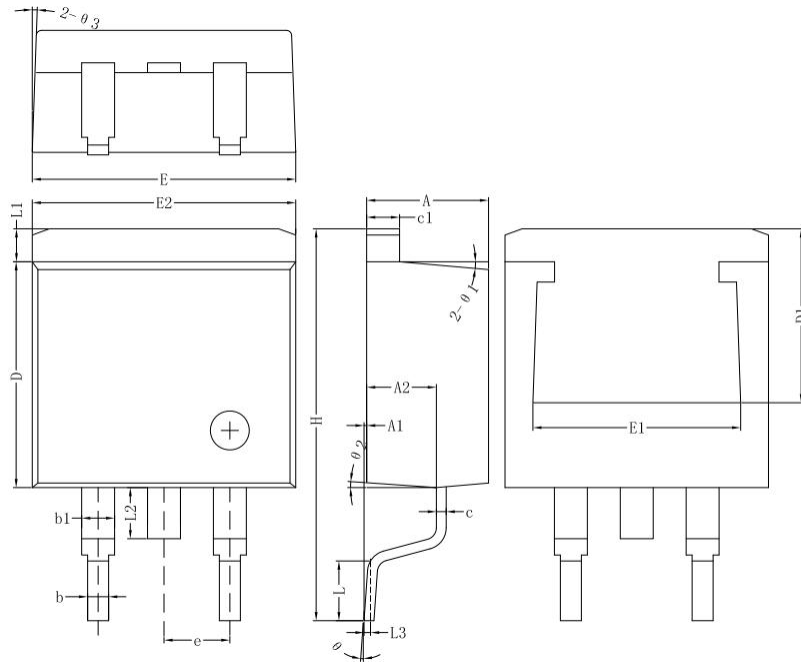


Mechanical Dimensions
TO-263-2 (Package 1)
Unit: mm


Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.57	4.70
A1	0.00	0.10	0.25
A2	2.59	2.69	2.79
b	0.77	-	0.90
b1	0.76	0.81	0.86
b2	1.23	-	1.36
b3	1.22	1.27	1.32
c	0.34	-	0.47
c1	0.33	0.38	0.43
c2	1.22	-	1.32
D	9.05	9.15	9.25
D1	6.60	-	-
E	10.06	10.16	10.26
E1	7.80	-	8.20
e	2.54(BSC)		
H	14.70	15.10	15.50
L	2.00	2.30	2.60
L1	1.17	1.27	1.40
L2	-	-	1.75
L3	0.25BSC		
L4	2.00REF		
θ	0°	-	8°
θ1	5°	7°	9°
θ2	1°	3°	5°

Mechanical Dimensions
TO-263-2 (Package 2)

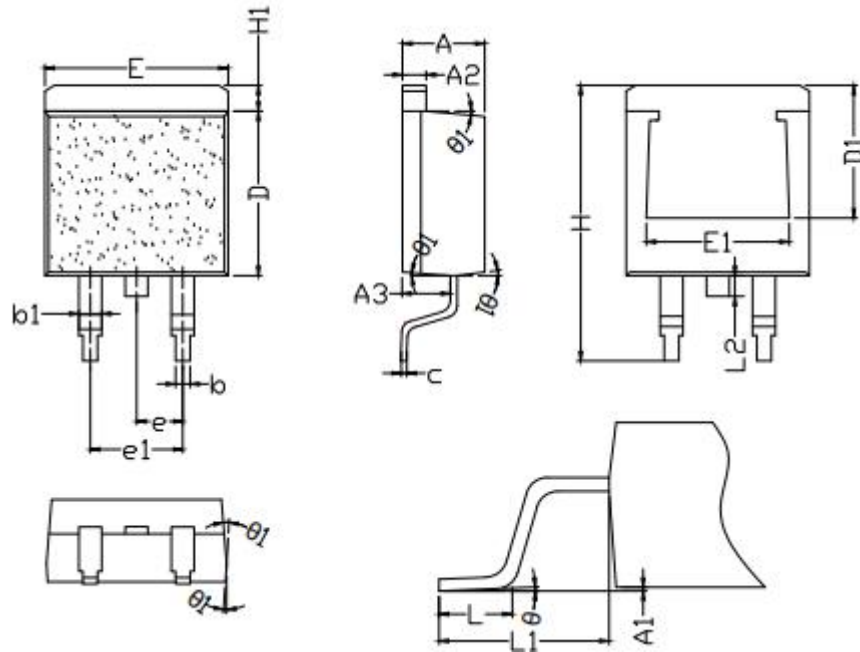
Unit: mm



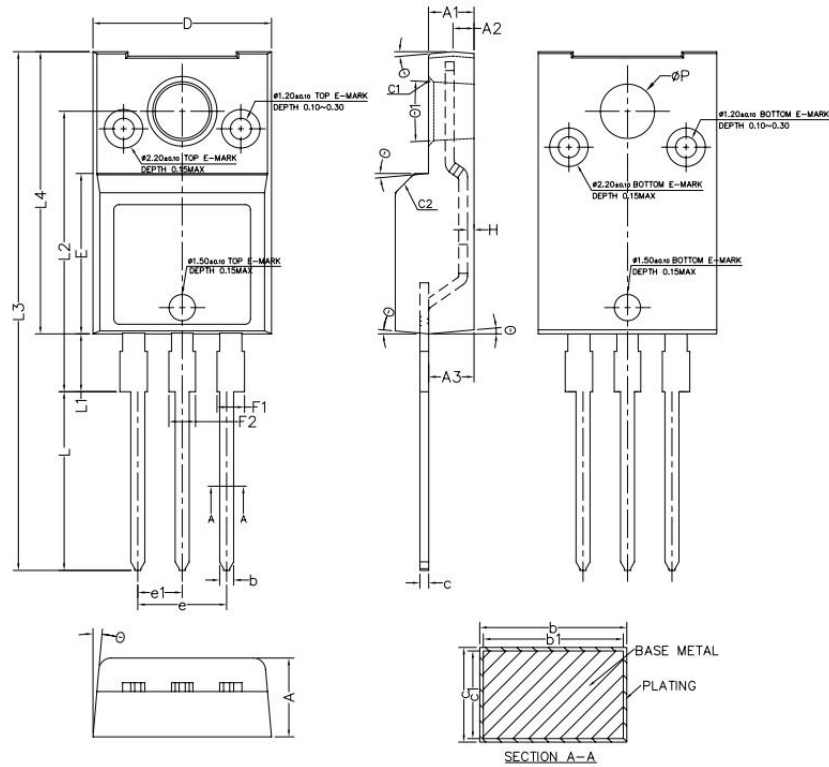
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.55	4.70	4.85
A1	0.00	0.10	0.25
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1	-	1.27	-
c	0.36	0.38	0.61
c1	1.17	1.27	1.37
D	8.55	8.70	8.85
D1	-	7.2	-
E	10.01	10.16	10.31
E1	-	7.80	-
E2	9.98	10.08	10.18
e	-	2.54	-
H	14.70	15.10	15.50
L	2.00	2.30	2.70
L1	1.17	1.27	1.40
L2	-	-	2.20
L3	-	0.25BSC	-
θ	0°	-	8°
θ1		5°	
θ2		4°	
θ3		4°	

Mechanical Dimensions
TO-263-2 (Package 3)

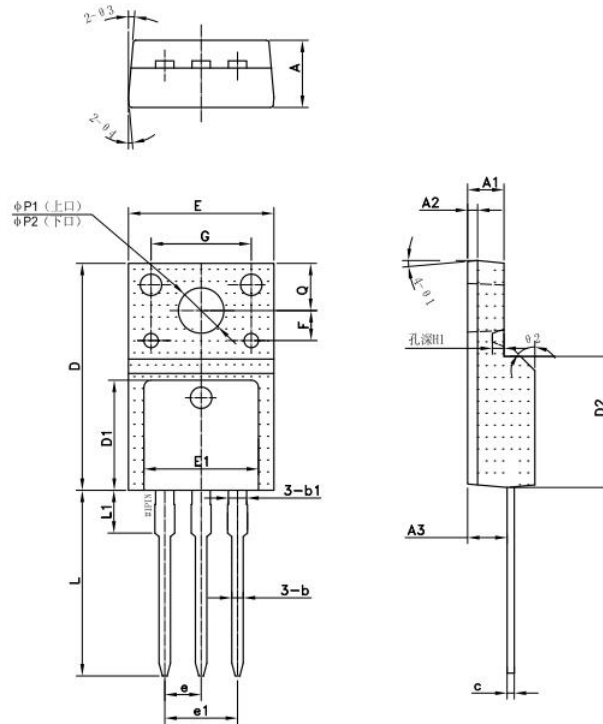
Unit: mm



Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.42	4.52	4.62
A1	0.00	0.10	0.25
A2	1.24	1.27	1.32
A3	2.50	2.60	2.70
b	0.77	0.81	0.84
b1	1.23	1.28	1.41
c	0.33	0.38	0.43
D	8.80	8.95	9.10
D1	7.2REF		
E	9.92	10.07	10.22
E1	7.85REF		
e	2.50	2.54	2.58
e1	5.08REF		
H	14.80	15.10	15.30
H1	1.12	1.28	1.42
L	2.10	2.23	2.36
L1	4.55	4.75	4.95
L2	1.10	1.30	1.50
θ	0°	2°	5°
θ1	3°	-	5°

Mechanical Dimensions
TO-220F (Package 1)
Unit: mm


Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.50	4.60
A1	2.50	2.60	2.70
A2	1.10	1.20	1.30
A3	2.49	2.59	2.69
b	0.76	-	0.89
b1	0.75	0.80	0.85
c	0.46	-	0.59
c1	0.45	0.50	0.55
C1	0.20	0.30	0.40
C2	1.00	1.10	1.20
D	10.10	10.20	10.30
E	9.05	9.15	9.25
e	4.98	5.08	5.18
e1	2.44	2.54	2.64
F1	1.22	-	1.60
F2	1.17	-	1.55
H	0.32	0.37	0.42
L	10.00	10.20	10.40
L1	3.15	3.30	3.45
L2	15.85	16.00	16.15
L3	29.30	29.60	29.90
L4	16.00	16.10	16.20
P	3.00	3.10	3.20
θ	3°	5°	7°
θ1	4°	6°	8°

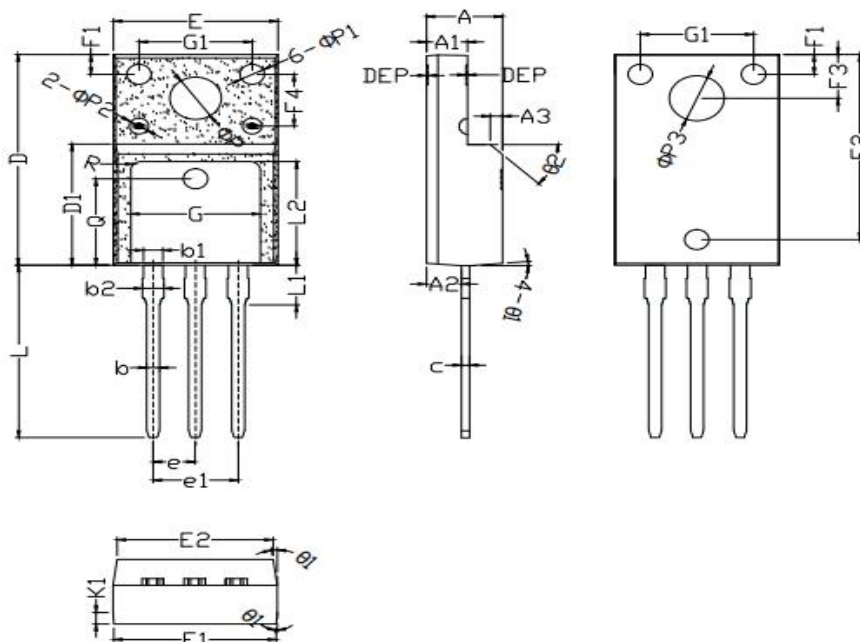
Mechanical Dimensions
TO-220F (Package 2)
Unit: mm


Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.50	4.70	4.90
A1	2.34	2.54	2.70
A2	-	0.70	-
A3	2.56	2.76	2.96
b	0.70	0.80	0.95
b1	-	1.28	-
c	0.45	0.50	0.65
D	15.67	15.87	16.07
D1	-	7.70	-
D2	-	9.12	-
E	9.96	10.16	10.36
E1	-	8.00	-
e	2.54		
e1		5.08	
F		2.1	
G		7	
H1	-	0.81	-
L	12.48	12.98	13.20
L1	-	2.93	-
ΦP1 (上口)	2.98	3.18	3.38
ΦP2 (下口)	3.20	3.40	3.60
Q	3.10	3.30	3.50
θ1		5°	
θ2		45°	
θ2		5°	
θ3		5°	

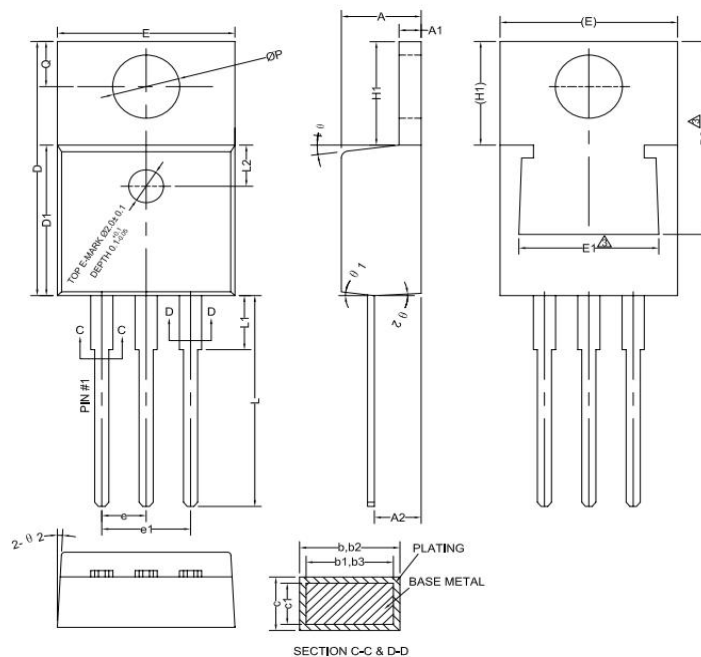
Mechanical Dimensions

TO-220F (Package 3)

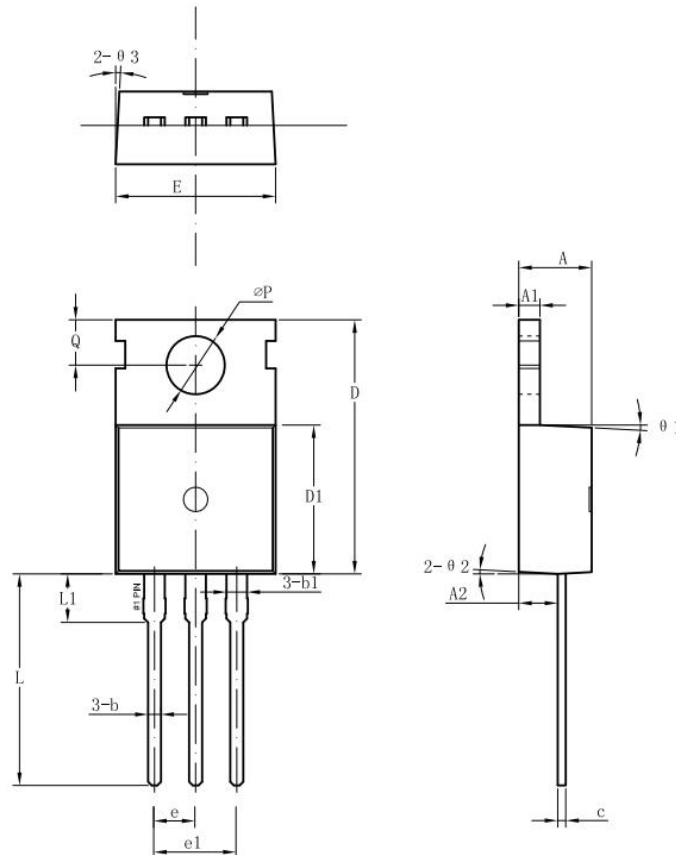
Unit: mm



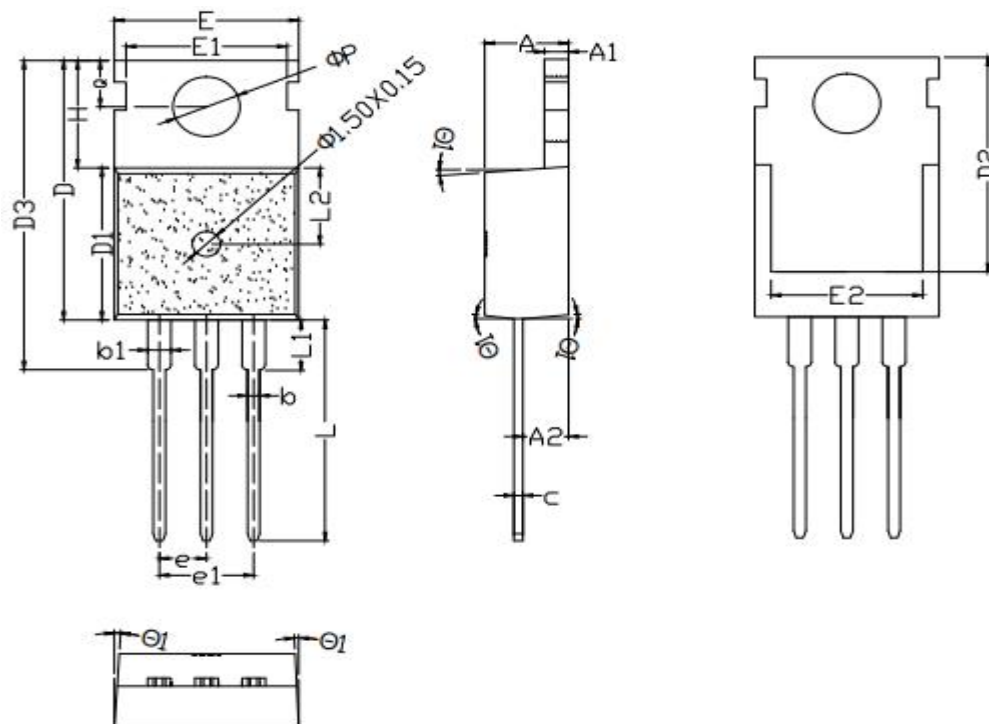
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.50	4.70	4.90
A1	2.34	2.54	2.74
A2	2.60	2.80	2.95
A3	1.0REF		
b	0.75	0.80	0.85
b1	1.18	1.20	1.24
b2	1.18	1.24	1.30
c	0.45	0.50	0.55
D	15.67	15.87	16.07
D1	9.04	9.12	9.20
E	10.00	10.16	10.30
E1	9.94	10.06	10.30
E2	9.40	9.50	9.60
e	2.50	2.54	2.58
e1	5.08REF		
L	12.78	12.98	13.18
L1	2.70	2.92	3.20
L2	7.70	7.80	7.90
Q	6.50REF		
ΦP	3.08	3.18	3.28
ΦP1	1.45	1.55	1.65
ΦP2	0.95	1.15	1.35
ΦP3	3.30	3.40	3.50
θ1	3°	5°	7°
θ2	42°	45°	48°
F1	1.40	1.50	1.60
F2	13.80	13.90	14.00
F3	3.20	3.30	3.40
F4	3.70	3.90	4.10
G	7.80	8.00	8.20
G1	6.90	7.00	7.10
K1	0.65	0.70	0.75

Mechanical Dimensions
TO-220C (Package 1)
Unit: mm


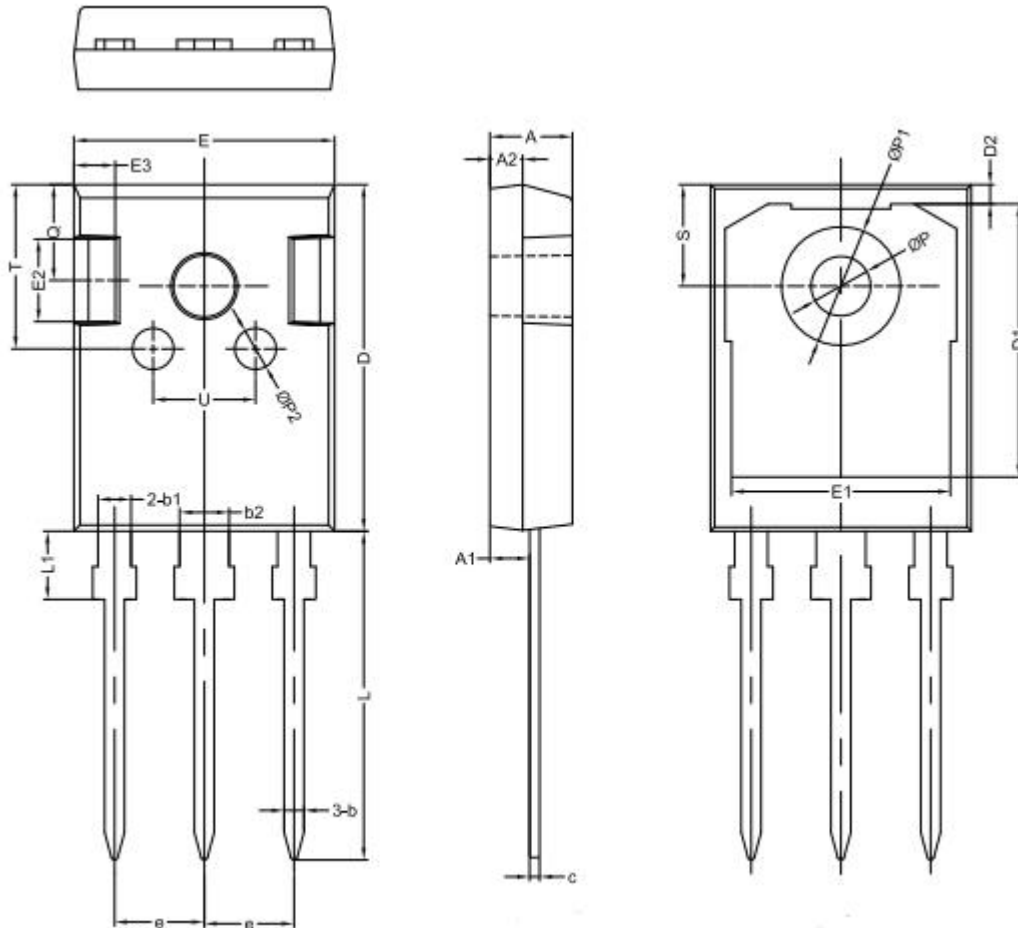
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.57	4.70
A1	1.22	-	1.32
A2	2.59	2.69	2.79
b	0.77	-	0.90
b1	0.76	0.81	0.86
b2	1.23	-	1.36
b3	1.22	1.27	1.32
c	0.34	-	0.47
c1	0.33	0.38	0.43
D	15.15	15.45	15.75
D1	9.05	9.15	9.25
D2	11.40	-	12.88
E	9.96	10.16	10.36
E1	6.86	-	8.89
e	2.44	2.54	2.64
e1	4.98	5.08	5.18
H1	6.10	6.30	6.50
L	12.70	-	13.12
L1	-	-	3.90
ØP	3.80	3.84	3.88
Q	2.60	-	2.90
θ1	5°	7°	9°
θ2	1°	2°	5°

Mechanical Dimensions
TO-220C (Package 2)
Unit: mm


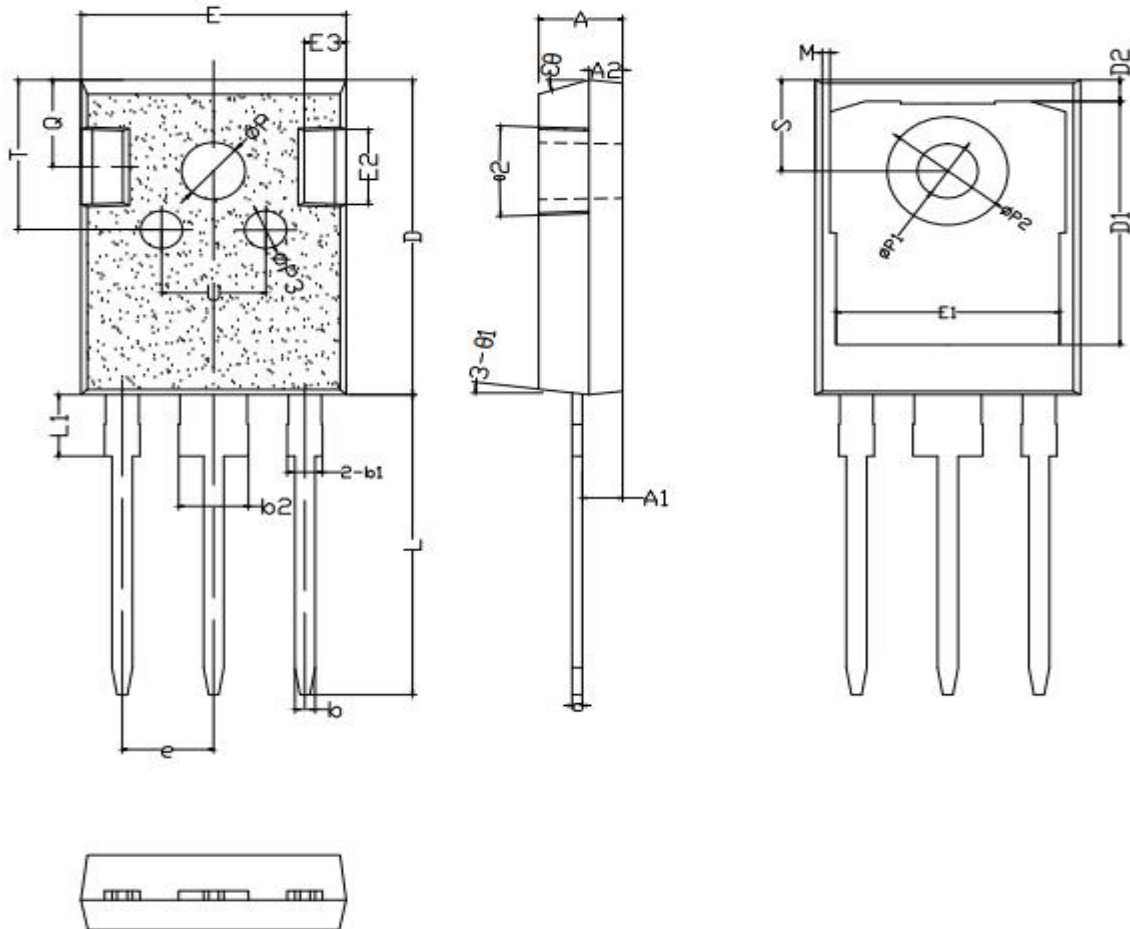
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.30	4.50	4.70
A1	1.25	1.30	1.40
A2	2.20	2.40	2.60
b	0.70	0.80	0.95
b1	-	1.27	-
c	0.40	0.50	0.65
D	15.20	15.70	16.20
D1	9.00	9.20	9.40
E	9.70	10.00	10.20
e		2.54	
e1		5.08	
L	12.60	13.08	13.60
L1	-	3.00	-
ΦP	3.50	3.60	3.80
Q	2.60	2.80	3.00
θ1		3°	
θ2		3°	
θ3		3°	

Mechanical Dimensions
TO-220C (Package 3)
Unit: mm


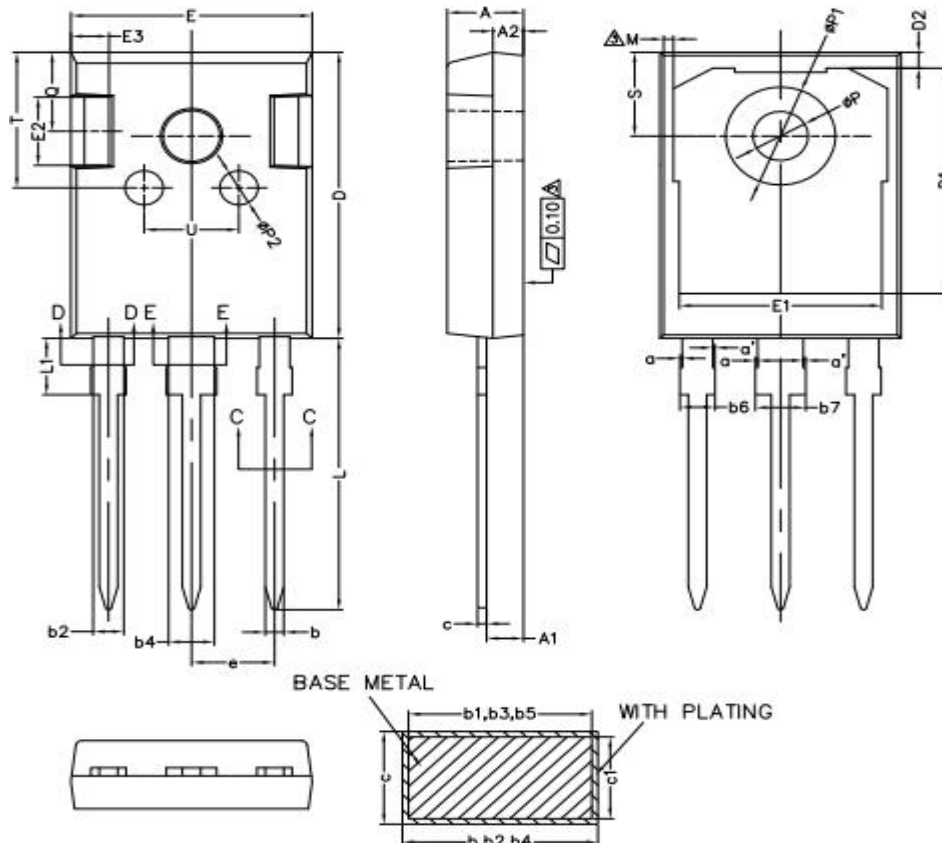
Symbol	Dimensions(mm)		
	Min.	Typ.	Max.
A	4.40	4.50	4.60
A1	1.25	1.30	1.35
A2	2.30	2.40	2.50
b	0.70	0.80	0.90
b1	1.25	1.33	1.42
c	0.45	0.50	0.55
D	15.50	15.75	16.00
D1	9.10	9.20	9.30
D2	12.90	13.10	13.30
D3	15.45	15.80	16.15
E	9.80	10.02	10.15
e	2.54BSC		
e1	5.08BSC		
L	13.00	13.28	13.45
L1	-	-	3.40
ΦP	3.55	3.65	3.75
Q	2.65	2.75	2.85
θ1	2°	-	7°
E1	8.55	8.70	8.85
E2	7.40	7.60	7.80
H	6.40	6.50	6.60
L2	4.50	4.65	4.80

Mechanical Dimensions
TO-247(Package 1)
Unit: mm


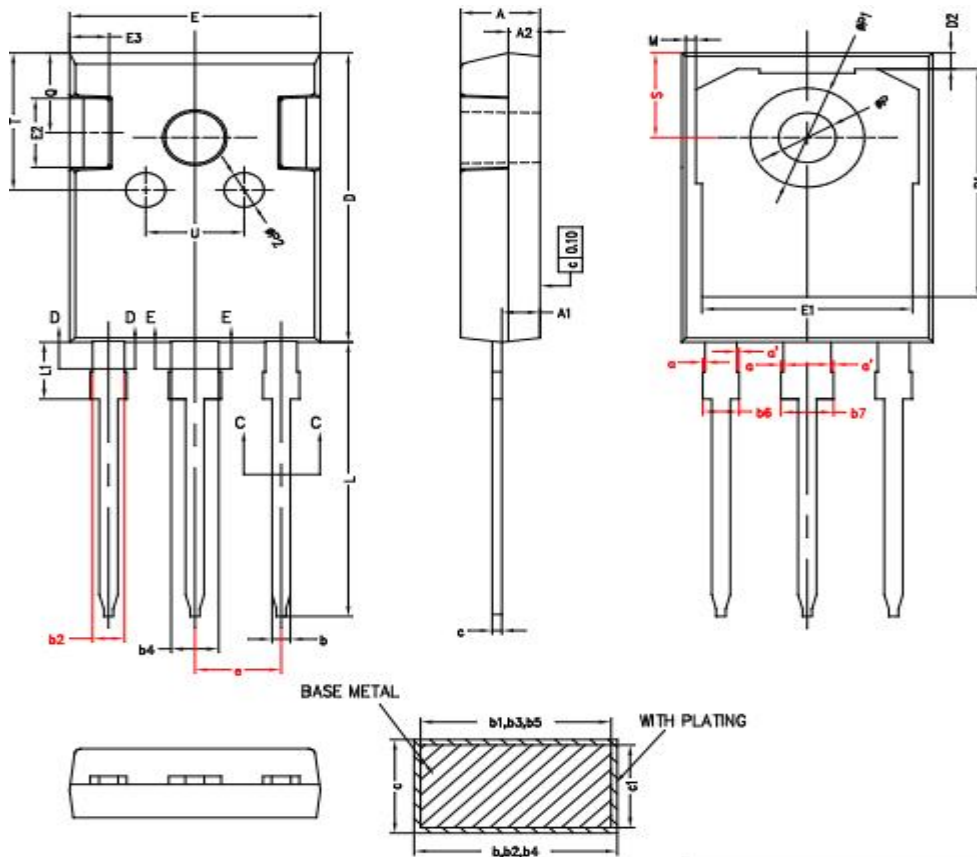
Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.80	5.00	5.20	E1	-	13.30	-
A1	2.21	2.41	2.61	E2	-	5.00	-
A2	1.90	2.00	2.10	E3	-	2.50	-
b	1.10	1.20	1.35	L	19.42	19.92	20.42
b1	-	2.00	-	L1	-	4.13	-
b2	-	3.00	-	P	3.50	3.60	3.70
c	0.55	0.60	0.75	P1	-	7.19	-
D	20.80	21.00	21.20	P2	-	2.50	-
D1	-	16.55	-	Q	-	5.80	-
D2	-	1.20	-	S	6.05	6.15	6.25
E	15.60	15.80	16.0	T	-	10.00	-
U	-	6.20	-				

Mechanical Dimensions
TO-247(Package 2)
Unit: mm


Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.90	5.00	5.10	E1	13.10	13.25	13.40
A1	2.31	2.41	2.51	E2	4.85	4.95	5.10
A2	1.90	2.00	2.10	E3	2.40	2.50	2.60
b	1.15	1.20	1.25	L	19.80	19.98	20.15
b1	1.95	2.10	2.25	L1	-	-	4.30
b2	2.95	3.10	3.25	ΦP	3.60	3.70	3.80
c	0.55	0.60	0.65	ΦP1	3.40	3.50	3.60
D	20.90	21.00	21.10	ΦP2	6.90	7.10	7.30
D1	16.35	16.55	16.75	Q	5.60	5.80	6.00
D2	1.05	1.20	1.35	S	6.05	6.15	6.25
E	15.70	15.80	15.90	T	9.80	10.00	10.20
U	6.00	6.20	6.40	e	5.40	5.44	5.48
Ø1	5°	7°	9°	ΦP3	2.40	2.50	2.60
Ø2	1°	3°	5°	Ø3	13°	15°	17°

Mechanical Dimensions
TO-247(Package 3)
Unit: mm


Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.90	5.00	5.10	c1	0.58	0.60	0.62
A1	2.31	2.41	2.51	D	20.90	21.00	21.10
A2	1.90	2.00	2.10	D1	16.25	16.55	16.85
b	1.16	-	1.26	D2	1.05	1.20	1.35
b1	1.15	1.20	1.22	E	15.70	15.80	15.90
b2	1.96	-	2.06	E1	13.10	13.30	13.50
b3	1.95	2.00	2.02	E2	4.90	5.00	5.10
b4	2.96	-	3.06	E3	2.40	2.50	2.60
b5	2.95	3.00	3.02	e	5.34	5.44	5.54
b6	-	-	2.25	L	19.80	19.92	20.10
b7	-	-	3.25	L1	3.95	4.13	4.30
c	0.59	-	0.66	M	0.35	-	0.95
P	3.50	3.60	3.70	P1	7.00	-	7.40
P2	2.40	2.50	2.60	Q	5.60	-	6.00
S	6.05	6.15	6.25	T	9.80	-	10.20
U	6.00	-	6.40	a	0	-	0.15
a'	0	-	0.15				

Mechanical Dimensions
TO-247(Package 4)
Unit: mm


Symbol	Dimensions(mm)			Symbol	Dimensions(mm)		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.90	5.00	5.10	E2	4.90	5.00	5.10
A1	2.31	2.41	2.51	E3	2.40	2.50	2.60
A2	1.90	2.00	2.10	e	5.34	5.44	5.54
b	1.12	-	1.22	L	19.80	19.92	20.10
b1	1.11	1.16	1.18	L1	3.95	4.13	4.30
b2	1.96	-	2.06	P	3.50	3.60	3.70
c	0.59	-	0.66	P1	7.00	-	7.40
D	20.90	21.00	21.10	P2	2.40	2.50	2.60
D1	16.25	16.55	16.85	Q	5.60	-	6.00
D2	1.05	1.20	1.35	S	6.05	6.15	6.25
E	15.70	15.80	15.90	T	9.80	-	10.20
E1	13.10	13.30	13.50	U	6.00	-	6.40
b3	1.95	2.00	2.02	b6	-	-	2.25
b4	2.96	-	3.06	b7	-	-	3.25
b5	2.95	3.00	3.02	c1	0.58	0.60	0.62
M	0.35	-	0.95	a	0	-	0.15
a'	0	-	0.15				



Shenzhen Sanrise Technology Co., LTD

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Main Site:

- Headquarter

Shenzhen Sanrise Technology Co., LTD.
A1206, Skyworth building, No. 008, gaoxinnan 1st Road,
Gaoxin District, Yuehai street,, Nanshan District, ShenZhen,
P.R.China

Tel: +86-755-22953335

Fax: +86-755-22916878

- Shanghai Office

Shenzhen Sanrise Technology Co., LTD
Rm.401, Building B, No. 666, Zhangheng Road,
Zhangjiang Hi-Tech Park, Shanghai, P.R.China

Tel: +86-21-68825918